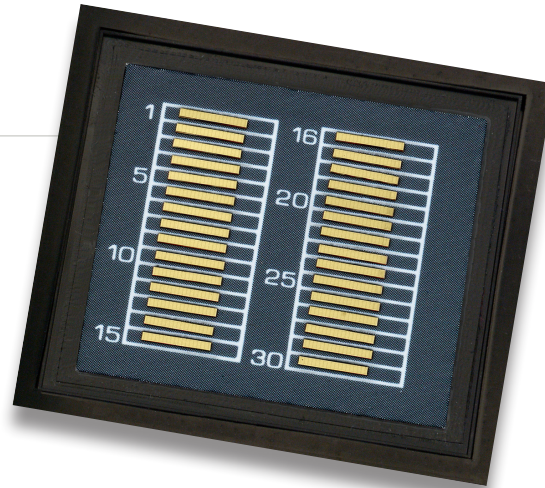


PART NUMBER: UMB700P200  
LASER DIODE BAR

#### FEATURES AND BENEFITS



- Excellent Solderability

- Available With Any Golden Bullet® Configuration

- Lot Tested

- Available Wavelengths (790-980nm)

#### OPTICAL CHARACTERISTICS

Parameter	Conditions	Min	Typ	Units
QCW Power Output	180A at 25°C Heat Sink	200	—	W
Operating Current	200W at 25°C Heat Sink	—	180	A
Threshold Current	25°C Heat Sink	—	15	A
Slope Efficiency	25°C Heat Sink	—	1.2	W/A
Efficiency	200W at 25°C Heat Sink	—	55	%
Number of Emitters	—	—	52	
Emitter Size	—	—	150x1	µm
Emitter Pitch	—	—	180	µm
Center Wavelength	200W at 25°C Heat Sink	—	808	nm
Wavelength Tolerance	200W at 25°C Heat Sink	—	+/-3	nm
Spectral Width	200W at 25°C Heat Sink	—	2.5	nm
Wavelength Shift	—	—	0.25	nm/°C
Beam Divergence FWHM	—	—	40x10	°x°
Polarization	—	—	TE	

#### ELECTRICAL CHARACTERISTICS

Parameter	Conditions	Min	Typ	Units
Series Resistance	25°C Heat Sink	—	0.002	ohms
Operating Voltage	25°C Heat Sink, 200W	—	2.0	V

#### MECHANICAL CHARACTERISTICS

Parameter	Typical
Bar Width	9.6 mm
Bar Thickness	135 µm
Bar Cavity Length	1000 µm

#### NOTES

(1) These specifications apply for operation at 808nm. Other wavelengths available upon request.

(2) A dry nitrogen environment should be provided by the user when storing and operating at temperatures below ambient dew point.



光技術をサポートする  
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200W QCW

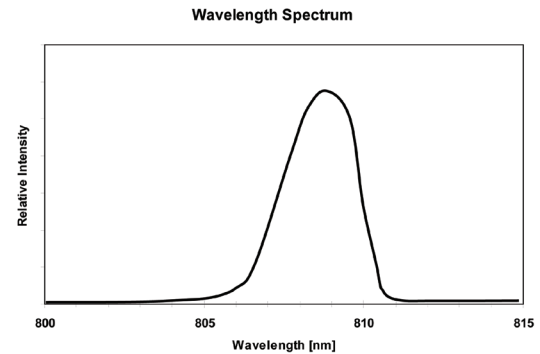
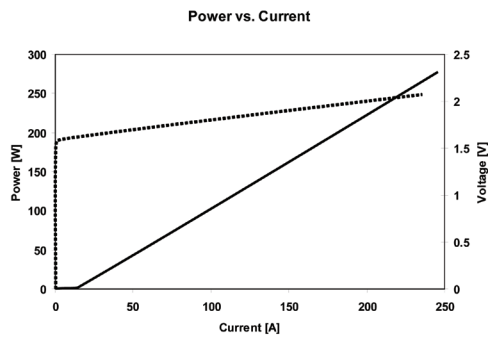
> ABSOLUTE MAXIMUM RATINGS

Parameter	Conditions
Reverse Current	0 A
Reverse Voltage	0 V
Operating Temperature Range	-40°C to 70°C
Storage Temperature Range	-40°C to 85°C

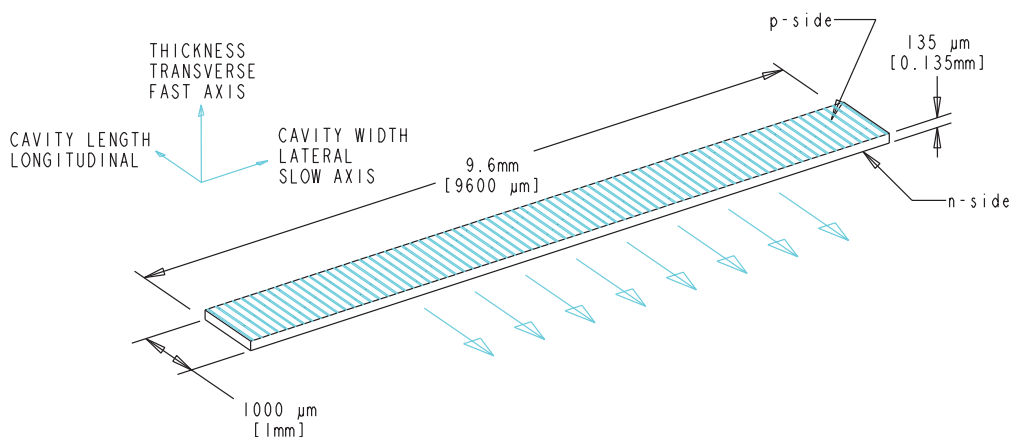
> SOLDERING CHARACTERISTICS

Parameter	Conditions
Metalization	1000 Å Au over Pt barrier

> OPTICAL CHARACTERISTICS (TYPICAL)



> MECHANICAL CHARACTERISTICS



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**⚠ DANGER ⚠**

INVISIBLE LASER RADIATION  
AVOID EYE OR SKIN EXPOSURE TO DIRECT OR SCATTERED RADIATION

\* Diode laser  
SW & lq. 790-1560nm  
CLASS IV

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**⚠ WARNING ⚠**

ELECTROSTATIC DISCHARGE SENSITIVE DEVICE  
REQUIRING SPECIAL HANDLING

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